

Evaluating CWDM 10GBASE-SX

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PMD Solutions - 4X CWDM

>CWDM 10GBASE-SX - multi-mode only

>Installed multi-mode 100m

>New MMF 550m

>CWDM 10GBASE-LX

► Installed multi-mode 300m

≻New MMF 300m

>Single-mode 10km





- > Uses available low cost silicon technology
- Uses inexpensive multi-mode optics & lasers
- Meets 100 and 300 meter distance objective
- > Meets economic criteria
- >1/3 the cost of CWDM 10GBASE-LX
- >1/3 the cost of 850nm 10G serial





> Uses available low cost silicon technology

>TIA

CMOS technology

>PHY Interface

CMOS technology

>2.4GHz Silicon Detectors on-hand



LOW COST and LOW RISK





- Uses inexpensive multi-mode optics & lasers
- >plastic optics
- >low cost multi-mode sources
- > fast and easy assembly





> Meets 100 meter distance objective

CWDM 10GBASE-SX 100m

CWDM 10GBASE-LX

>850nm 10G Serial

>1300nm 10G Serial

300m at 3 X cost

30m at 3 X cost

80m at 3 X cost





> Meets 300 meter distance objective

CWDM 10GBASE-SX 550m

CWDM 10GBASE-LX

>850nm 10G Serial

>1300nm 10G Serial

300m at 3 X cost

300m at 3 X cost

80m at 3 X cost





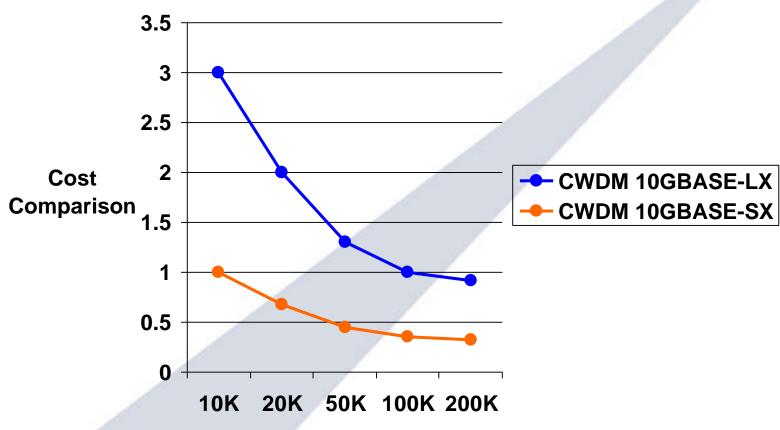
- > Meets economic criteria*
- ➤ "A target cost increase of 3X 1000 BASE X...."
- CWDM 10GBASE-SX meets this criteria at 100K piece quantities

> *HSSG, 5 Criteria, Economic Feasibility, September York

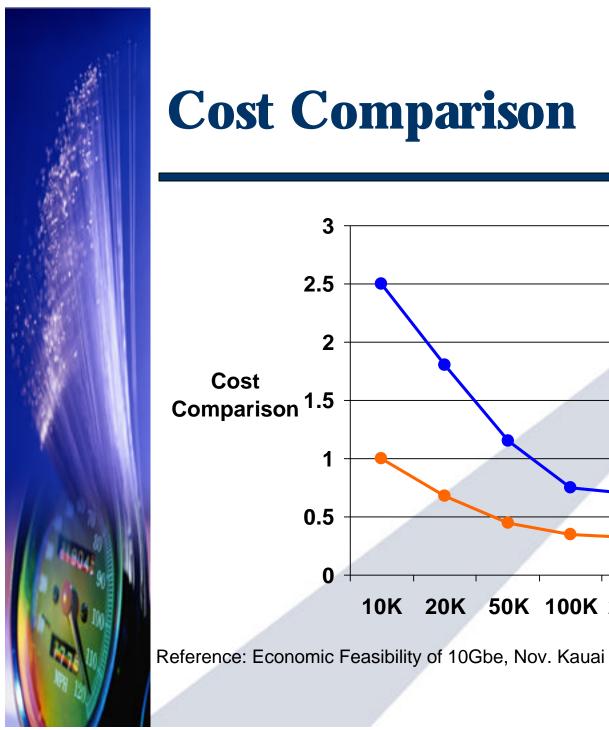




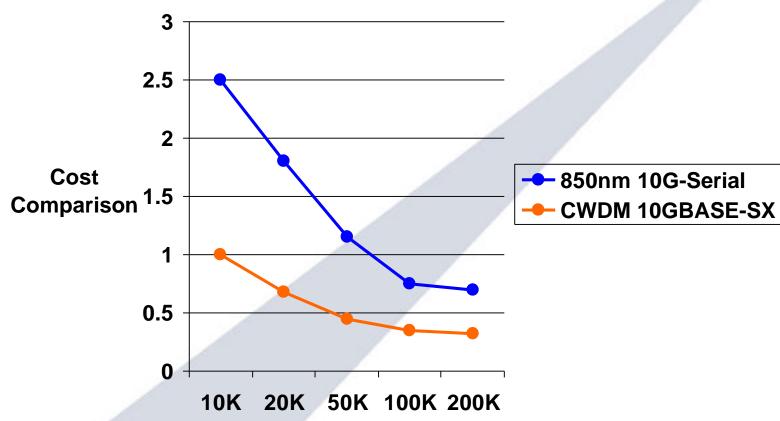
Cost Comparison







Cost Comparison





CWDM 10GBASE-SX 10Gig-Serial Cost Comparison

- CWDM 10GBASE-SX is inherently less expensive than 10Gig-Serial
- Four silicon detectors are much less expensive than **one** InGaAs
- CMOS is less expensive than higher speed alternatives





Early Availability

- CWDM 10GBASE-SX Q4 2000*
- CWDM 10GBASE-LX Q4 2000*
- Early availability at attractive pricing helps to provide the important early adoption of 10G products

> *Pre-standard silicon, standards-based silicon Q2 2001





Technical Feasibility

>Mux/Demux Plastic molded optic Now

Detectors Silicon Now

► Sources Oxide VCSELs Now*

>Filters Wafer grown Now

≻TIAs Silicon Dev**

>PHY intface Silicon Dev

>Standard assembly techniques Now

*specific wavelengths under development

> **2.5Gbits TIA available today





10GBASE-SX Remaining Issues

- General Availability
- > Cost
- ≻Open Fiber Control





Table 38-6 Operating Range

Fiber Type	Modal bandwidth @ 850 nm (min. overfilled launch) (MHz*km)	Minimum range (meters)
62.5 μm MMF	160	2-100
50.0 μm MMF	500	2-300
50.0 μm MMF (new)	2200*	2-550

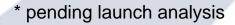






Table 38-7 Transmit

Description	62.5 mm MMF 50 mm MMF 50 mm MMF (new)	Unit
Transmitter Type	Shortwave Laser	
Signaling speed per channel (range)	$2.578\pm100~\mathrm{ppm}^{^{\star}}$	GBd
Wavelength (range), four channels	805 to 895	nm
Channel center wavelengths	812.5, 837.5, 862.5, 887.5 ± 6.3 nm	nm
Channel separation	25.0	nm
Trise/Tfall (max. 20-80% response time)	100	ps
RMS spectral width (max)	0.5	nm
Average launch power, four channels (max)	+4.7	dBm
Average launch power per channel (max)	-1.3	dBm
Average launch power per channel (min)	-5.5	dBm
Extinction ratio, (min)	7	dB
RIN (max)	-117	dB/Hz

^{* 64}B/66B coding





Table 38-8 Receive

Description	62.5 mm MMF 50 mm MMF	50 mm MMF	50 mm MMF (new)	Unit
Signaling speed per channel (range)	2.578 ± 100 ppm*		GBd	
Wavelength (range), four channels	805 to 895		nm	
Channel center wavelengths	812.5, 837.5, 862.5, 887.5		nm	
	± 6.3 nm			
Channel separation	25.0		nm	
Average receive power, four channels (max)	4.7		dBm	
Average receive power, per channel (max)	-1.3		dBm	
Return loss	12		dB	
Receive electrical 3 dB upper cutoff frequency (min)	2000		MHz	
Receive sensitivity	-13.5	-13.5	-13.5	dBm
Stressed receive sensitivity	-8	-9.0	-10.4	dBm
Vertical eye closure penalty	2.9	2.7	0.9	dB

^{* 64}B/66B coding





Table 39-9 Link Power Budget

Parameter	62.5 μm MMF	50.0 μm MMF	50.0 μm MMF (new)	Unit
Modal bandwidth as measured at 850 nm (min overfilled launch)	160	500	2200	MHz*km
Link power budget	8.0	8.0	8.0	dB
Operating distance	100	300	550	m
Channel insertion loss	2.03	3.10	4.44	dB
Link power penalties	3.64	3.50	1.84	dB
Unallocated margin in link power budget	2.33	1.39	1.72	dB





Evaluating PMDs

	Objectives & Criteria				
PMD Proposal	100m on Installed MMF	300m on New MMF	2Km on SMF	10Km on SMF	40Km on SMF
CWDM 850nm	Yes	Yes	No	No	No
Serial 850nm	No	Yes	No	No	No
Serial 1300nm (FP)	No	No	Yes	No	No
Serial 1300nm (DFB/VCSEL)	No	No	Yes	Yes	No
CWDM 1300nm	Yes	Yes	Yes	Yes	No
Serial 1300nm (Cooled DFB)	No	No	Yes	Yes	~Yes
Serial 1500nm	No	No	Yes	Yes	Yes